

INCHANGE SEMICONDUCTOR

isc Silicon NPN Darlington Power Transistor

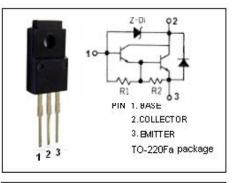
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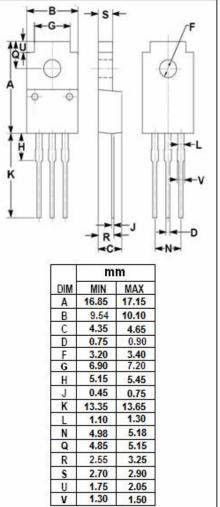
DESCRIPTION

- High DC Current Gain-
- : h_{FE} = 1000(Min)@ I_C= 1A
- Low Collector-Emitter Saturation Voltage-
- : V_{CE(sat)} = 1.5V(Max)@ I_C= 1A
- Incorporating a built-in zener diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Low-frequency power amplifier amplifications.





ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	SYMBOL PARAMETER		UNIT	
V _{сво}	Collector-Base Voltage	80-110	V	
V _{CEO}	Collector-Emitter Voltage	80-110	V	
V _{EBO}	Emitter-Base Voltage	6	V	
lc	Collector Current-Continuous	2	A	
I _{CM}	Base Current-Peak	3	A	
Pc	Collector Power Dissipation @ $T_c=25^{\circ}C$	20	W	
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	°C	



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1mA; I _B = 0	80		110	V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C =0.1mA; I _E = 0	80		110	V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 3mA; I _C = 0	5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 1A; I _B = 1mA			1.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 1A; I _B = 1mA			2.0	V
I _{CBO}	Collector Cutoff Current	V_{CB} = 70V; I _E = 0			10	μ Α
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			3.0	mA
h _{FE}	DC Current Gain	I _C = 1A; V _{CE} = 2V	1000		10000	
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V;f _{test} = 1.0MHz		25		pF
f _T	Current-Gain—Bandwidth Product	I _C = 0.1A ; V _{CE} = 5V		80		MHz

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